

◆ 2 W

- 薄膜
- 高衰减精度
- 低驻波比
- 陶瓷芯片：99% 氧化铝
- 激光调阻
- 高性价比

X - 焊接方式 A or B or C
XX - 衰减量: **dB.
XX - 频率范围 06: DC to 6GHz
 10: DC to 10GHz
 12: DC to 12.4GHz
 18: DC to 18GHz
 26: DC to 26.5GHz.
 A: 金丝键合
 B: 无铅回流焊
 C: 包三边

频率范围	DC to 18 GHz
衰减量	10 dB
衰减精度（典型值）	± 0.5 dB DC to 4 GHz + 0.5 dB 4 to 8 GHz + 0.75 dB 8 to 12.4 GHz + 1.0 dB 12.4 to 18 GHz
衰减稳定度	0.0001 dB/dB/°C
阻抗	50 Ohm
额定输入功率	2 W
工作温度	-55 °C to +150 °C

频率范围 (GHz)	VSWR(:1)典型值
DC to 4	1.05
4 to 8	1.20
8 to 12.4	1.25
12.4 to 18	1.40

Figure 1: Dimensions of the package. The figure shows three views of a package: a top view, a side view, and a cross-sectional view. The top view shows a rectangular package with a central square area. Dimensions include a total width of 3.68, a central square width of 1.70, and a central square height of 1.50. The side view shows a height of 3.10 and a thickness of 0.41. The cross-sectional view shows a central square area with a width of 1.70 and a height of 1.50, and a central square area with a width of 1.70 and a height of 1.50. The package is labeled 'TYP' and 'MIN'.

介质基板	99% 氧化铝
电极	金钛钨合金 金厚度 : $3\text{ }\mu\text{m}$
电阻	TaN 薄膜

环境温度 (°C)	额定功率百分比 (%)
-55	100
100	100
150	0

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